

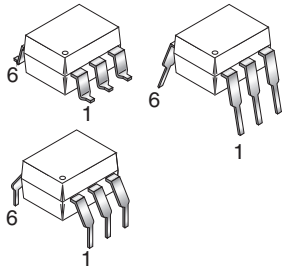
**MCT2
MCT2200**

**MCT2E
MCT2201**

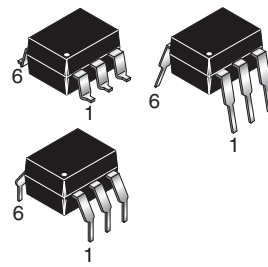
**MCT210
MCT2202**

MCT271

WHITE PACKAGE (-M SUFFIX)



BLACK PACKAGE (NO -M SUFFIX)



DESCRIPTION

The MCT2XXX series optoisolators consist of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a 6-pin dual in-line package.

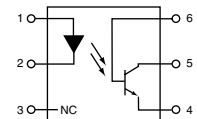
FEATURES

- UL recognized (File # E90700)
- VDE recognized (File # 94766)
 - Add option V for white package (e.g., MCT2V-M)
 - Add option 300 for black package (e.g., MCT2.300)
- MCT2 and MCT2E are also available in white package by specifying -M suffix, eg. MCT2-M

APPLICATIONS

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

SCHEMATIC



PIN 1. ANODE
2. CATHODE
3. NO CONNECTION
4. EMITTER
5. COLLECTOR
6. BASE

MCT2
MCT2200

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ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Device	Value	Units
TOTAL DEVICE Storage Temperature	T_{STG}	ALL	-55 to +150	°C
Operating Temperature	T_{OPR}	ALL	-55 to +100	°C
Lead Solder Temperature	T_{SOL}	ALL	260 for 10 sec	°C
Total Device Power Dissipation @ $T_A = 25^{\circ}\text{C}$	P_D	-M	250	mW
		Non-M	260	
Derate above 25°C		-M	2.94	mW/°C
		Non-M	3.3	
EMITTER DC/Average Forward Input Current	I_F	-M	60	mA
		Non-M	100	
Reverse Input Voltage	V_R	ALL	3	V
Forward Current - Peak (300µs, 2% Duty Cycle)	$I_F(pk)$	ALL	3	A
LED Power Dissipation @ $T_A = 25^{\circ}\text{C}$	P_D	-M	120	mW
		Non-M	150	
Derate above 25°C		-M	1.41	mW/°C
		Non-M	2.0	
DETECTOR Collector Current	I_C	ALL	50	mA
Collector-Emitter Voltage	V_{CEO}	ALL	30	V
Detector Power Dissipation @ $T_A = 25^{\circ}\text{C}$	P_D	ALL	150	mW
Derate above 25°C		-M	1.76	mW/°C
		Non-M	2.0	

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

Individual Component Characteristics

Parameter	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
EMITTER							
Input Forward Voltage	(I _F = 20 mA)	V _F	MCT2/-M MCT2E/-M MCT271 MCT2200 MCT2201 MCT2202		1.25	1.50	V
	(T _A = 0-70°C, I _F = 40 mA)		MCT210		1.33		
Reverse Leakage Current	(V _R = 3.0 V)	I _R	MCT2/-M MCT2E/-M MCT271 MCT2200 MCT2201 MCT2202		0.001	10	μA
	(T _A = 0-70°C, V _R = 6.0 V)		MCT210				
DETECTOR		BV _{CEO}	ALL	30	100		V
Collector-Emitter Breakdown Voltage	(I _C = 1.0 mA, I _F = 0) (T _A = 0-70°C)		MCT210				
Collector-Base Breakdown Voltage	(I _C = 10 μA, I _F = 0)	BV _{CBO}	MCT2/-M MCT2E/-M MCT271 MCT2200 MCT2201 MCT2202	70	120		V
	(T _A = 0-70°C)		MCT210	30			
Emitter-Collector Breakdown Voltage	(I _E = 100 μA, I _F = 0)	BV _{ECO}	MCT2/-M MCT2E/-M MCT271 MCT2200 MCT2201 MCT2202	7	10		V
	(T _A = 0-70°C)		MCT210	6	10		
Collector-Emitter Dark Current	(V _{CE} = 10 V, I _F = 0)	I _{CEO}	ALL		1	50	nA
	(V _{CE} = 5 V, T _A = 0-70°C)					30	μA
Collector-Base Dark Current	(V _{CB} = 10 V, I _F = 0)	I _{CBO}	ALL			20	nA
Capacitance	(V _{CE} = 0 V, f = 1 MHz)	C _{CE}	ALL		8		pF

** Typical values at $T_A = 25^\circ\text{C}$

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TRANSFER CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

DC Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
Output Collector Current	(T _A = 0-70°C)	CTR	MCT210	150			%
	(I _F = 10 mA, V _{CE} = 5 V)		MCT2200	20			
			MCT2201	100			
			MCT2202	63		125	
	(I _F = 10 mA, V _{CE} = 10 V)		MCT2 MCT2-M MCT2E MCT2E-M	20			
			MCT271	45		90	
	(I _F = 3.2 mA to 32 mA, V _{CE} = 0.4 V) (T _A = 0-70°C)		MCT210	50			
Collector-Emitter Saturation Voltage	(I _C = 2 mA, I _F = 16 mA)	V _{CE (SAT)}	MCT2 MCT2-M MCT2E MCT2E-M MCT271			0.4	V
	MCT210						
	MCT2200 MCT2201 MCT2202						
AC Characteristic Saturated Turn-on Time from 5 V to 0.8 V	(I _F = 15 mA, V _{CC} = 5 V, R _L = 2 kΩ) (R _B = Open) (Fig. 20)	t _{on}	MCT2		1.1		μs
	(I _F = 20 mA, V _{CC} = 5 V, R _L = 2 kΩ) (R _B = 100 kΩ) (Fig. 20)		MCT2E		1.1		
			MCT2		1.3		
			MCT2E		1.3		
Saturated Turn-off Time from SAT to 2.0 V	(I _F = 15 mA, V _{CC} = 5 V, R _L = 2 kΩ) (R _B = Open) (Fig. 20)	t _{off}	MCT2		50		
	MCT2E			50			
	MCT2			20			
	MCT2E			20			
Turn-on Time	(I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω)	t _{on}	MCT2-M MCT2E-M		2		
Turn-off Time	(I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω)	t _{off}	MCT2-M MCT2E-M		2		
Rise Time	(I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω)	t _r	MCT2-M MCT2E-M		2		
Fall Time	(I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω)	t _f	MCT2-M MCT2E-M		1.5		

** Typical values at $T_A = 25^\circ\text{C}$

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TRANSFER CHARACTERISTICS (Cont.)

AC Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
Saturated turn-on time	$(I_F = 16 \text{ mA}, R_L = 1.9 \text{ k}\Omega, V_{CC} = 5 \text{ V})$ (Fig. 20)	t_{on}	MCT271		1.0		μs
Saturated turn-off time (Approximates a typical TTL interface)		t_{off}			48		
Saturated turn-on time	$(I_F = 16 \text{ mA}, R_L = 4.7 \text{ k}\Omega, V_{CC} = 5 \text{ V})$ (Fig. 20)	t_{on}			1.0		
Saturated turn-off time (Approximates a typical low power TTL interface)		t_{off}			98		
Saturated rise time	$(I_F = 16 \text{ mA}, R_L = 560 \Omega, V_{CC} = 5 \text{ V})$ (Fig. 20, 21)	t_r	MCT210		1.0		
Saturated fall time		t_f			11		
Saturated propagation delay - high to low	$(I_F = 16 \text{ mA}, R_L = 2.7 \text{ k}\Omega)$ (Fig. 20, 21)	$T_{PD} \text{ (HL)}$			1.0		
Saturated propagation delay - low to high		$T_{PD} \text{ (LH)}$			50		
Non-saturated turn on time	$(I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega)$ (Fig. 20)	T_{ON}	MCT2200		2	10	
Non-saturated turn off time		T_{OFF}	MCT2201 MCT2202		2	10	
Non-saturated rise time	$(I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 100 \Omega)$ (Fig. 20)	t_r	MCT210		2		
Non-saturated fall time		t_f			2		
Non-saturated turn-on time	$(I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 100 \Omega)$ (Fig. 20)	t_{on}	MCT271		2	7	
Non-saturated turn-off time		t_{off}			2	7	

** Typical values at $T_A = 25^\circ\text{C}$

ISOLATION CHARACTERISTICS

Characteristic	Test Conditions	Symbol	Min	Typ*	Max	Units
Input-Output Isolation Voltage	(Non '-M', Black Package) ($f = 60 \text{ Hz}, t = 1 \text{ min}$)	V_{ISO}	5300			Vac(rms)
	('M', White Package) ($f = 60 \text{ Hz}, t = 1 \text{ sec}$)		7500			Vac(pk)
Isolation Resistance	$(V_{I-O} = 500 \text{ VDC})$	R_{ISO}	10^{11}			Ω
Isolation Capacitance	$(V_{I-O} = \&, f = 1 \text{ MHz})$	C_{ISO}		0.5		pF
	('M' White Package)			0.2	2	pF

Note

* Typical values at $T_A = 25^\circ\text{C}$

**MCT2
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TYPICAL PERFORMANCE CURVES

Fig. 1 LED Forward Voltage vs. Forward Current (Black Package)

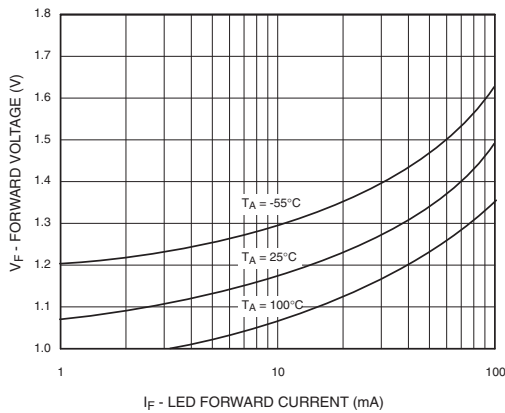


Fig. 2 LED Forward Voltage vs. Forward Current (White Package)

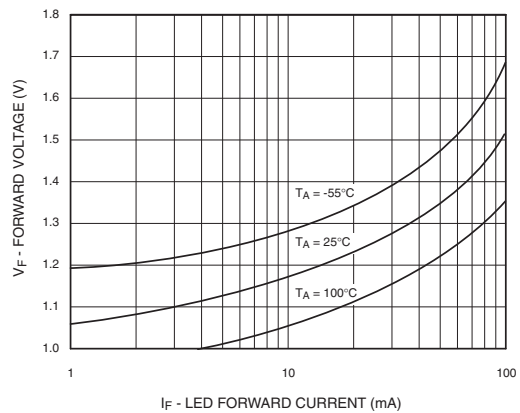


Fig.3 Normalized CTR vs. Forward Current (Black Package)

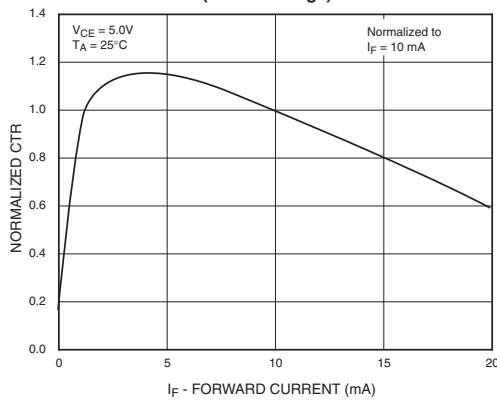


Fig.4 Normalized CTR vs. Forward Current (White Package)

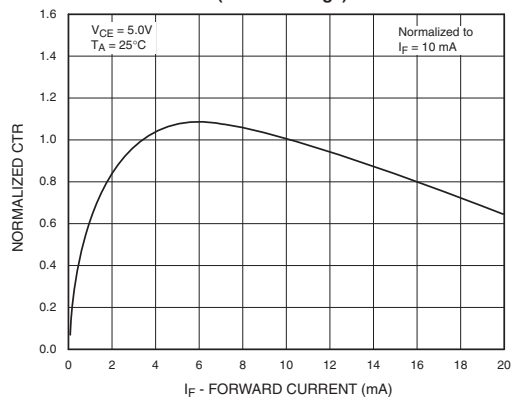


Fig. 5 Normalized CTR vs. Ambient Temperature (Black Package)

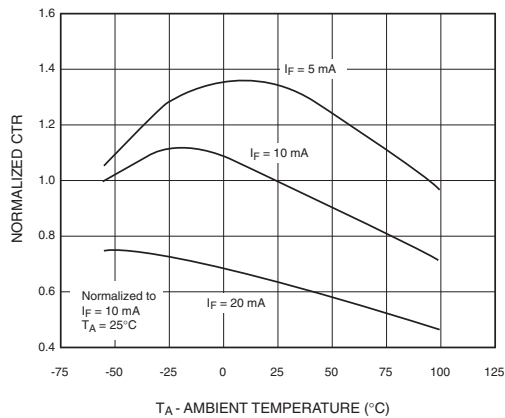
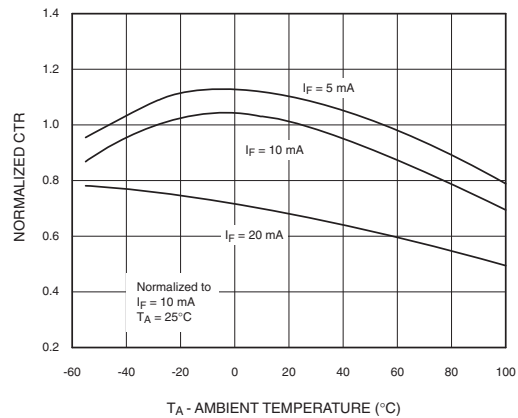


Fig. 6 Normalized CTR vs. Ambient Temperature (White Package)



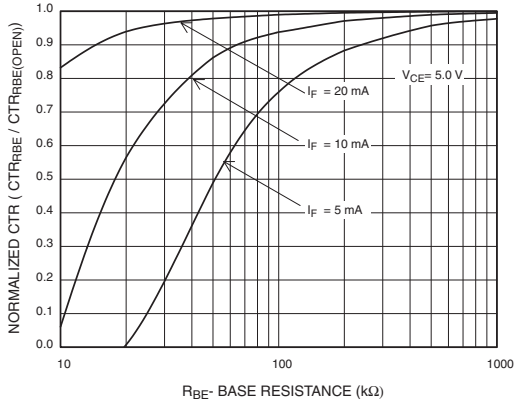
**MCT2
MCT2200**

**MCT2E
MCT2201**

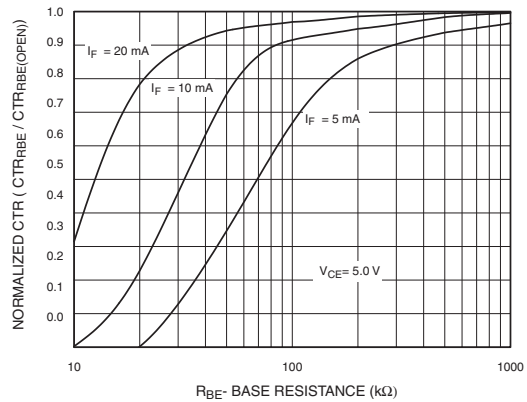
**MCT210
MCT2202**

MCT271

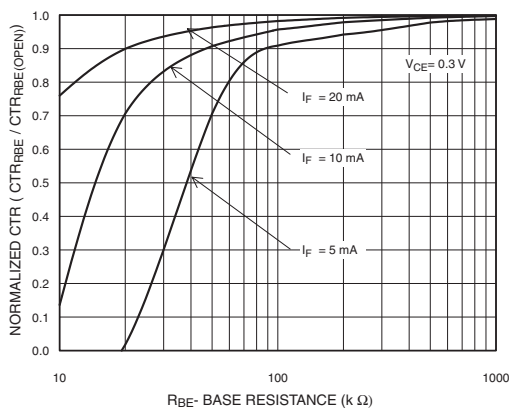
**Fig. 7 CTR vs. RBE (Unsaturated)
(Black Package)**



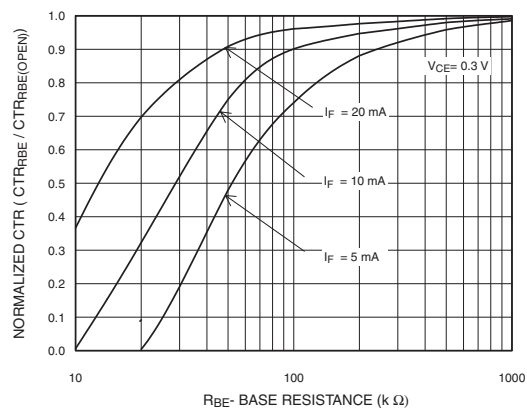
**Fig. 8 CTR vs. RBE (Unsaturated)
(White Package)**



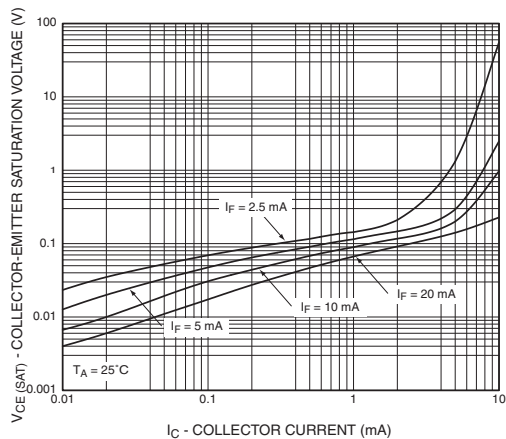
**Fig. 9 CTR vs. RBE (Saturated)
(Black Package)**



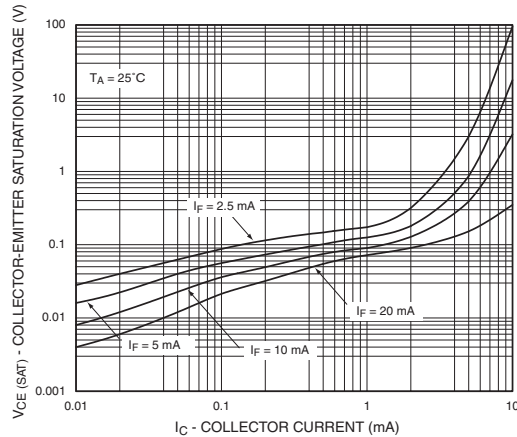
**Fig. 10 CTR vs. RBE (Saturated)
(White Package)**



**Fig. 11 Collector-Emitter Saturation Voltage vs. Collector Current
(Black Package)**



**Fig. 12 Collector-Emitter Saturation Voltage vs. Collector Current
(White Package)**



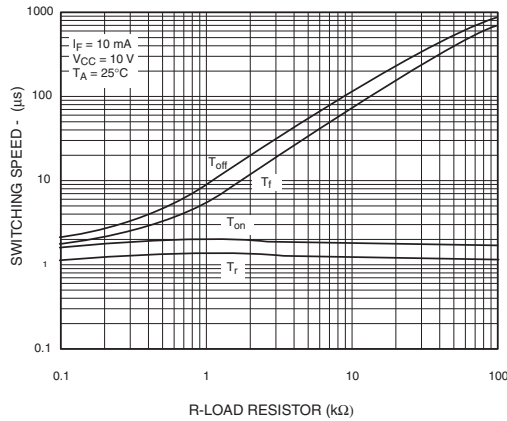
**MCT2
MCT2200**

**MCT2E
MCT2201**

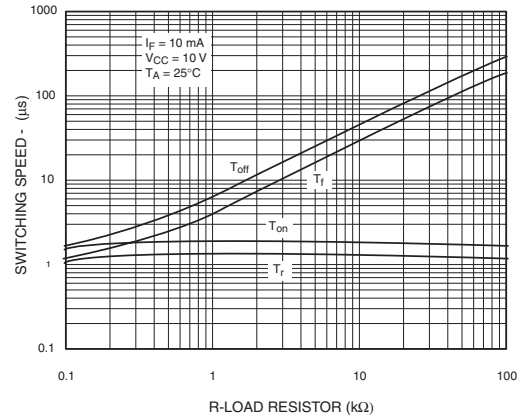
**MCT210
MCT2202**

MCT271

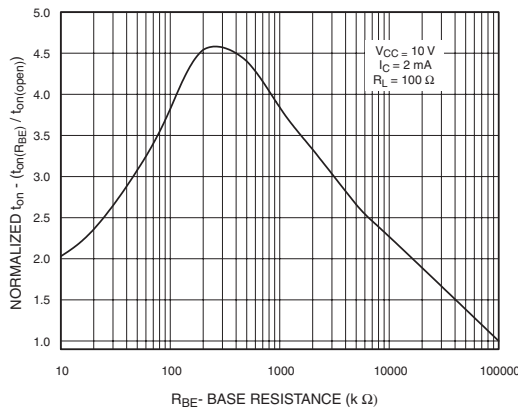
**Fig. 13 Switching Speed vs. Load Resistor
(Black Package)**



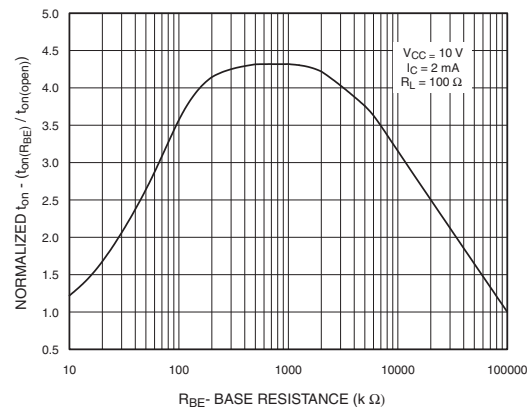
**Fig. 14 Switching Speed vs. Load Resistor
(White Package)**



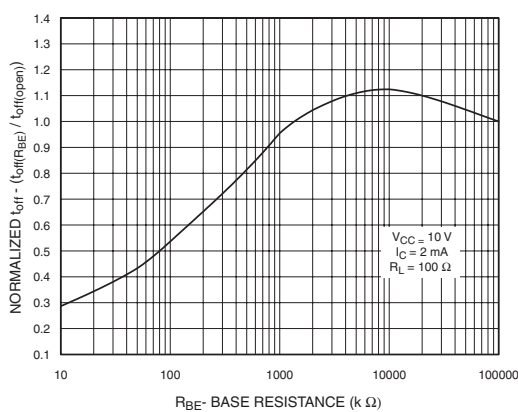
**Fig. 15 Normalized t_{on} vs. R_{BE}
(Black Package)**



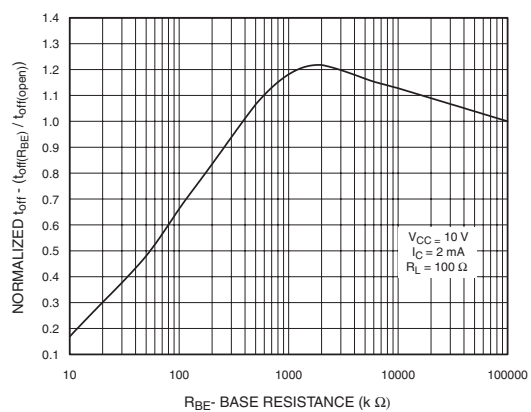
**Fig. 16 Normalized t_{on} vs. R_{BE}
(White Package)**



**Fig. 17 Normalized t_{off} vs. R_{BE}
(Black Package)**



**Fig. 18 Normalized t_{off} vs. R_{BE}
(White Package)**



**MCT2
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Fig. 19 Dark Current vs. Ambient Temperature

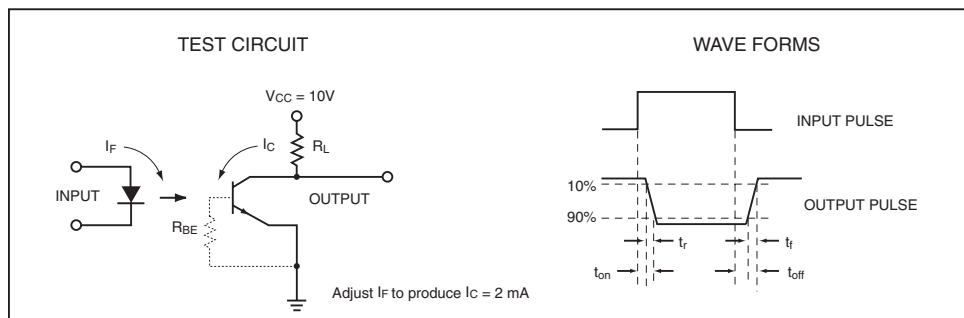
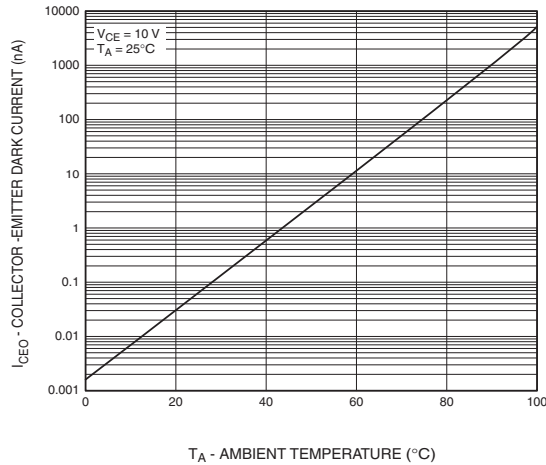


Figure 20. Switching Time Test Circuit and Waveforms

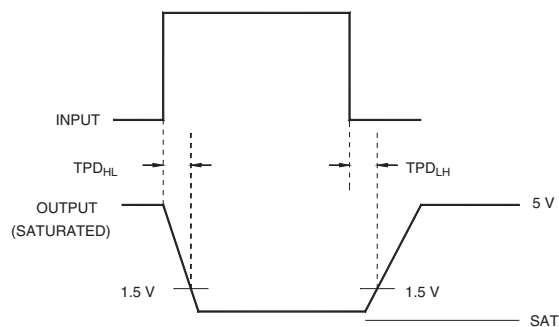


Figure 21. Switching Time Waveforms (MCT210)

**MCT2
MCT2200**

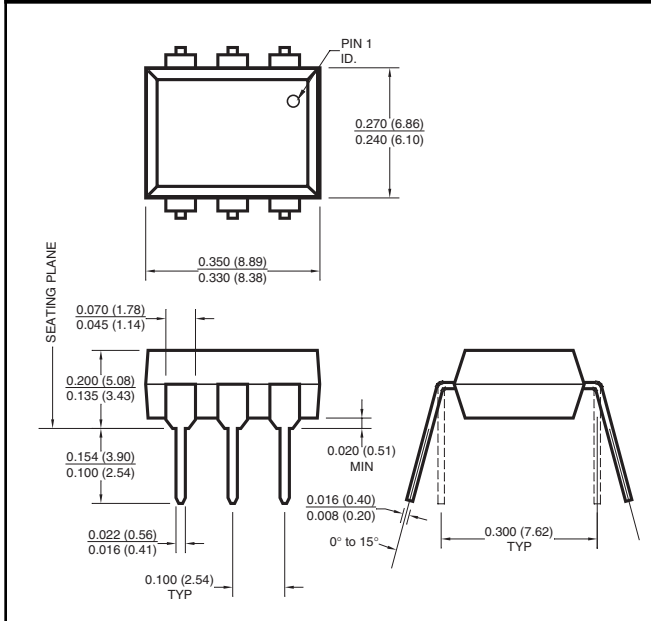
**MCT2E
MCT2201**

**MCT210
MCT2202**

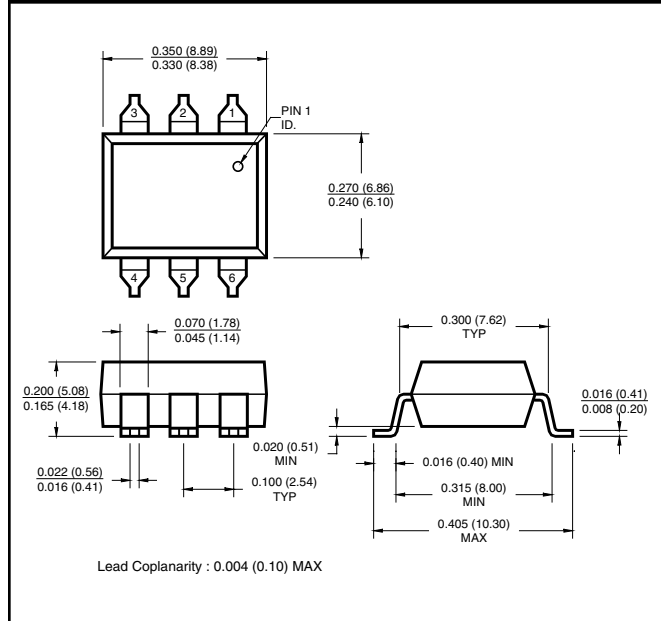
MCT271

Black Package (No -M Suffix)

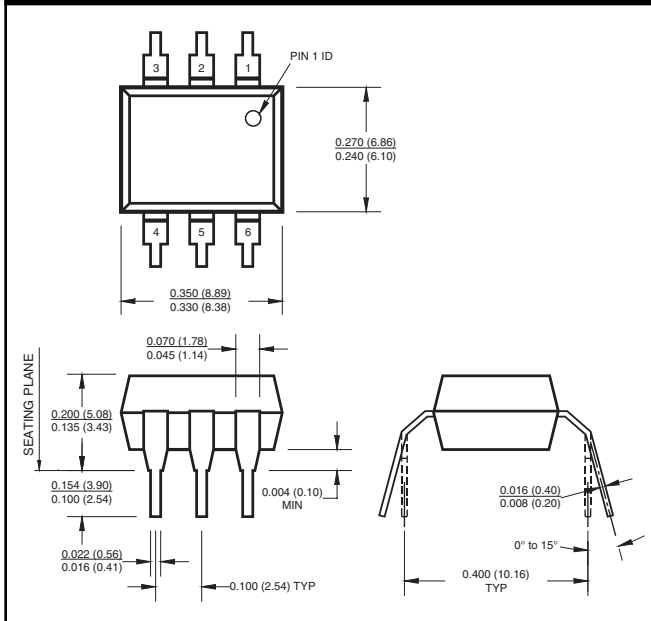
Package Dimensions (Through Hole)



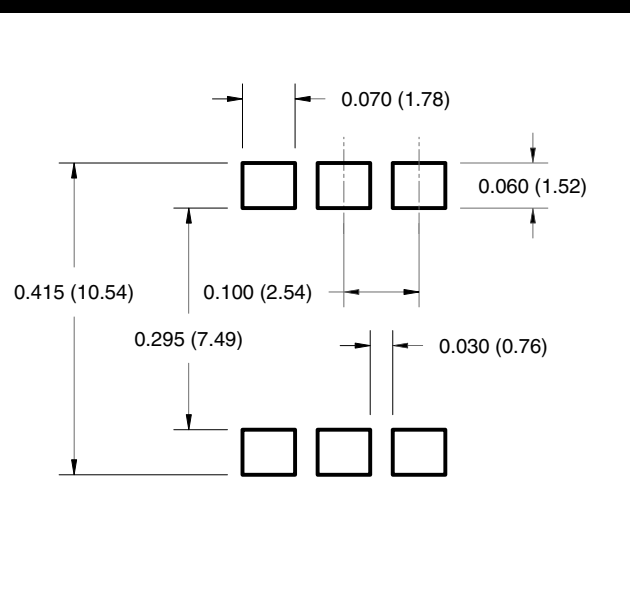
Package Dimensions (Surface Mount)



Package Dimensions (0.4" Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



NOTE

All dimensions are in inches (millimeters)

**MCT2
MCT2200**

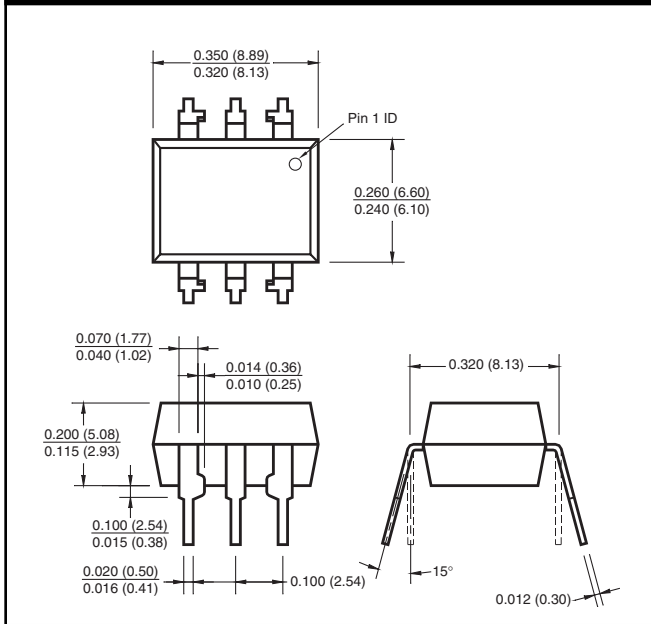
**MCT2E
MCT2201**

**MCT210
MCT2202**

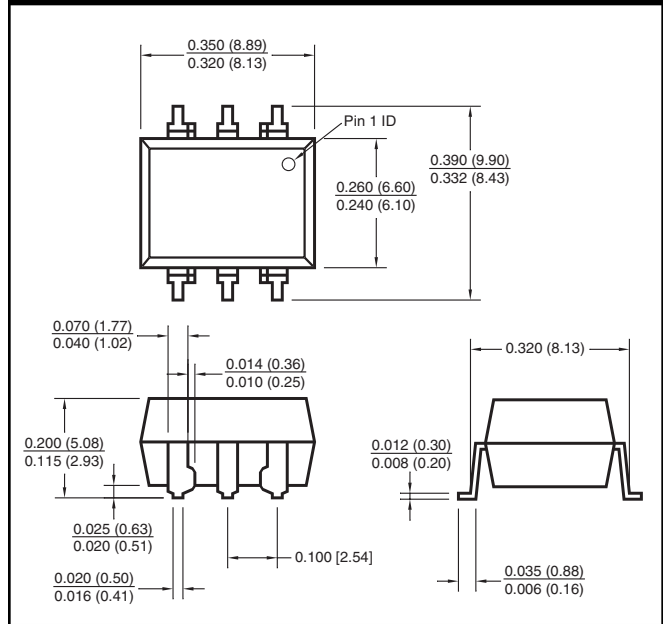
MCT271

White Package (-M Suffix)

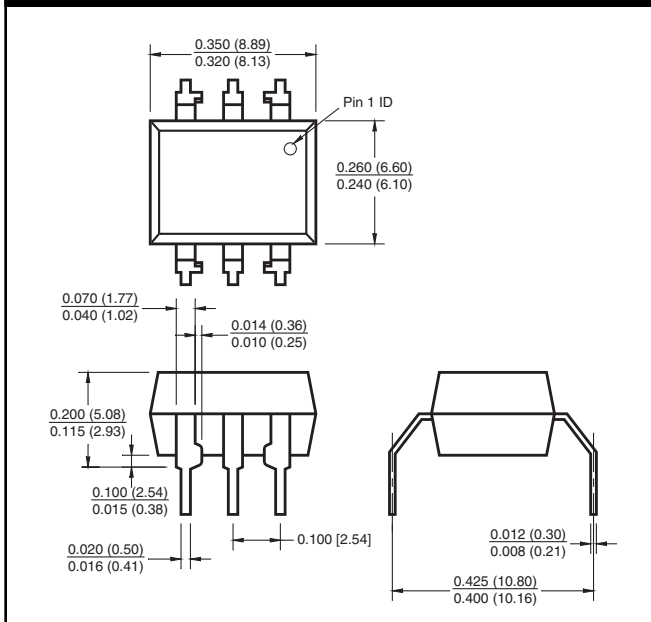
Package Dimensions (Through Hole)



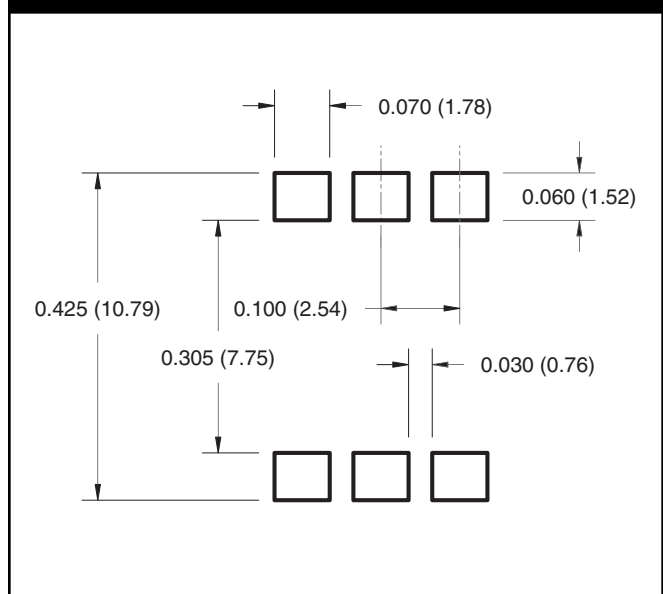
Package Dimensions (Surface Mount)



Package Dimensions (0.4" Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



NOTE

All dimensions are in inches (millimeters)

MCT2
MCT2200

MCT2E
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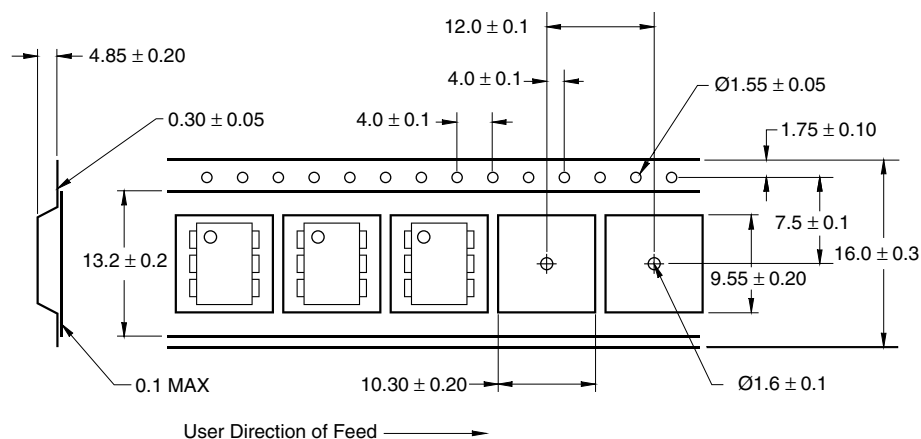
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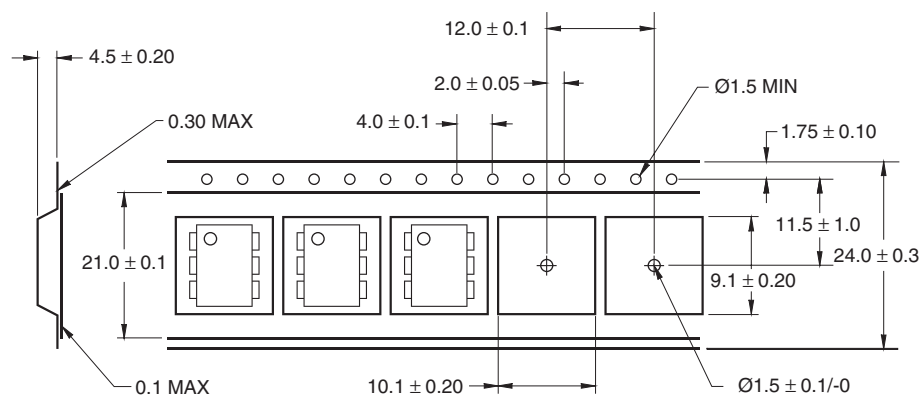
ORDERING INFORMATION

Order Entry Identifier		
Black Package (No Suffix)	White Package (-M Suffix)	Description
.S	S	Surface Mount Lead Bend
.SD	SR2	Surface Mount; Tape and reel
.W	T	0.4" Lead Spacing
.300	V	VDE 0884
.300W	TV	VDE 0884, 0.4" Lead Spacing
.3S	SV	VDE 0884, Surface Mount
.3SD	SR2V	VDE 0884, Surface Mount, Tape & Reel

QT Carrier Tape Specifications ("D" Taping Orientation) (Black Package, No Suffix)



QT Carrier Tape Specifications (“D” Taping Orientation) (White Package, -M Suffix)



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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.